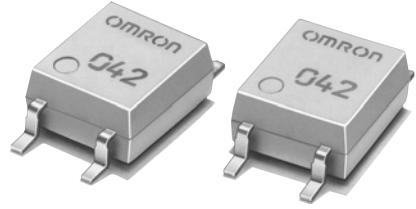


New MOS FET Relays with Low Output Capacitance and ON Resistance ($C_{xR} = 10\text{pF} \cdot \Omega$) in a 40-V Load Voltage Model.

- ON resistance of $2\ \Omega$ (typical) suppresses output signal attenuation.
- Leakage current of $1.0\ \text{nA}$ max. when output relay is open.
- RoHS compliant



Note. The actual product is marked differently from the image shown here.

■ Application Examples

- Semiconductor inspection tools
- Measurement devices
- Broadband systems
- Data loggers

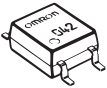
■ List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting terminals	40 VAC	G3VM-41GR4	100	
			G3VM-41GR4(TR)	–	2,500

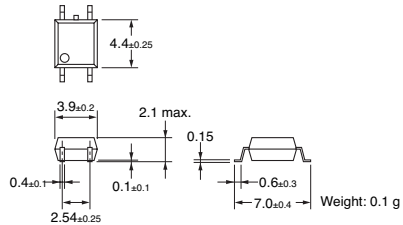
■ Dimensions

Note. All units are in millimeters unless otherwise indicated.

G3VM-41GR4

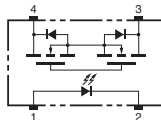


Note. The actual product is marked differently from the image shown here.



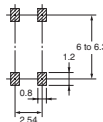
■ Terminal Arrangement/Internal Connections (Top View)

G3VM-41GR4



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-41GR4



Absolute Maximum Ratings (Ta = 25°C)

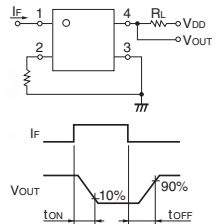
Item	Symbol	Rating	Unit	Measurement Conditions	
Input	LED forward current	I_F	50	mA	
	Repetitive peak LED forward current	I_{FP}	1	A	100 μ s pulses, 100 pps
	LED forward current reduction rate	$\Delta I_F/^\circ\text{C}$	-0.5	mA/°C	Ta \geq 25°C
	LED reverse voltage	V_R	5	V	
	Connection temperature	T_J	125	°C	
Output	Output dielectric strength	V_{OFF}	40	V	
	Continuous load current	I_O	250	mA	
	ON current reduction rate	$\Delta I_{ON}/^\circ\text{C}$	-2.5	mA/°C	Ta \geq 25°C
	Connection temperature	T_J	125	°C	
Dielectric strength between input and output (See note 1.)	V_{LO}	1,500	Vrms	AC for 1 min	
Operating temperature	T_{th}	-20 to +85	°C	With no icing or condensation	
Storage temperature	T_{stg}	-55 to +125	°C	With no icing or condensation	
Soldering temperature (10 s)	---	260	°C	10 s	

Note 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

Electrical Characteristics (Ta = 25°C)

Item	Symbol	Minimum	Typical	Maximum	Unit	Measurement conditions	
Input	LED forward voltage	V_F	1.0	1.15	1.3	V	$I_F = 10$ mA
	Reverse current	I_R	---	---	10	μ A	$V_R = 5$ V
	Capacity between terminals	C_F	---	15	---	pF	$V = 0$, $f = 1$ MHz
	Trigger LED forward current	I_{FT}	---	---	4	mA	$I_O = 100$ mA
Output	Maximum resistance with output ON	R_{ON}	---	2.0	3.0	Ω	$I_F = 5$ mA, $I_O = 250$ mA, $t < 1$ s
	Current leakage when the relay is open	I_{LEAK}	---	---	1.0	nA	$V_{OFF} = 30$ V, Ta = 50°C
	Capacity between terminals	C_{OFF}	---	5.0	7.0	pF	$V = 0$, $f = 100$ MHz, $t < 1$ s
Capacity between I/O terminals	C_{LO}	---	0.8	---	pF	$f = 1$ MHz, $V_S = 0$ V	
Insulation resistance	R_{LO}	1,000	---	---	M Ω	$V_{LO} = 500$ VDC, $R_{th} \leq 60\%$	
Turn-ON time	t_{ON}	---	---	0.5	ms	$I_F = 10$ mA, $R_L = 200 \Omega$	
Turn-OFF time	t_{OFF}	---	---	0.5	ms	$V_{DD} = 20$ V (See note 2.)	

Note 2. Turn-ON and Turn-OFF Times



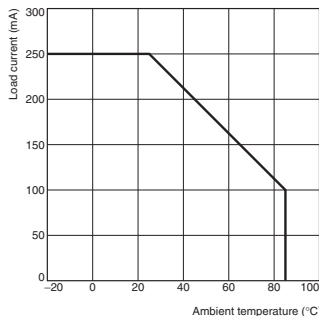
Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V_{DD}	---	---	32	V
Operating LED forward current	I_F	10	---	30	mA
Continuous load current	I_O	---	---	250	mA
Operating temperature	T_{th}	25	---	60	°C

Engineering Data

Load Current vs. Ambient Temperature G3VM-21GR1



Safety Precautions

Refer to "Common Precautions" for all G3VM models.